



SLPS208-AUGUST 2009 www.ti.com

## N-Channel NexFET™ Power MOSFET

#### **FEATURES**

- Ultra Low Qg and Qgd
- **Low Thermal Resistance**
- **Avalanche Rated**
- Pb Free Terminal Plating
- **RoHS Compliant**
- **Halogen Free**
- SON 5mm × 6mm Plastic Package

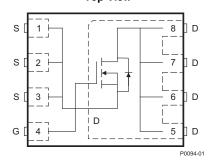
## **APPLICATIONS**

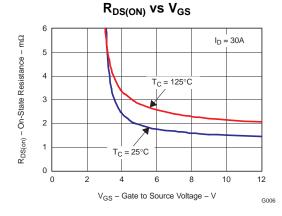
- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and **Computing Systems**
- **Optimized for Synchronous FET Applications**

## **DESCRIPTION**

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.







#### PRODUCT SUMMARY

$V_{DS}$	Drain to Source Voltage 25			V
$Q_g$	Gate Charge Total (4.5V)	16.6	nC	
$Q_{gd}$	Gate Charge Gate to Drain	4.4	nC	
D			2.1	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V 1.5		mΩ
$V_{GS(th)}$	Threshold Voltage	1.6		V

#### ORDERING INFORMATION

Device Package		Media	Qty	Ship
CSD16414Q5	SON 5 x 6 Plastic Package	13-inch reel	2500	Tape and Reel

#### **ABSOLUTE MAXIMUM RATINGS**

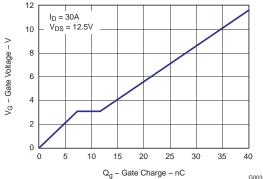
T <sub>A</sub> = 2	5°C unless otherwise stated	VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	25	V
$V_{GS}$	Gate to Source Voltage	+16 / -12	V
	Continuous Drain Current, T <sub>C</sub> = 25°C	100	Α
I <sub>D</sub>	Continuous Drain Current <sup>(1)</sup>	34	Α
$I_{DM}$	Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>	213	Α
P <sub>D</sub>	Power Dissipation <sup>(1)</sup>	3.2	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, single pulse $I_D$ = 100A, L = 0.1mH, $R_G$ = 25 $\Omega$	500	mJ

 $R_{\theta JA}$  = 39°C/W on 1in<sup>2</sup> Cu (2 oz.) on 0.060" thick FR4 PCB.

**Gate Charge** 

Pulse width ≤300µs, duty cycle ≤2%"





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## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Cl	naracteristics	·			
BV <sub>DSS</sub>	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25		V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 20V		1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>DS</sub> = 0V, V <sub>GS</sub> = +16/–12V		100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	1.3 1.6	2	V
D	Proin to Source On Registenes	$V_{GS} = 4.5V, I_D = 30A$	2.1	2.6	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 30A$	1.5	1.9	mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A	138		S
Dynamic	Characteristics				
C <sub>ISS</sub>	Input Capacitance		2810	3650	pF
Coss	Output Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 12.5V, f = 1MHz	2040	2650	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		140	180	pF
R <sub>g</sub>	Series Gate Resistance		1.4	2.8	Ω
Qg	Gate Charge Total (4.5V)		16.6	21	nC
Q <sub>gd</sub>	Gate Charge Gate to Drain	V 42.5V ID 20A	4.4		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	V <sub>DS</sub> = 12.5V, ID = 30A	7.3		nC
Qg(th)	Gate Charge at Vth		4.5		nC
Q <sub>OSS</sub>	Output Charge	V <sub>DS</sub> = 13.5V, VGS = 0V	40		nC
t <sub>d(on)</sub>	Turn On Delay Time		15		ns
t <sub>r</sub>	Rise Time	V <sub>DS</sub> = 12.5V, V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 30A	24		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$R_G = 2\Omega$	18.4		ns
t <sub>f</sub>	Fall Time		11.1		ns
Diode Cl	haracteristics				
V <sub>SD</sub>	Diode Forward Voltage	I <sub>S</sub> = 30A, V <sub>GS</sub> = 0V	0.81	1	V
Q <sub>rr</sub>	Reverse Recovery Charge	$V_{dd} = 13.5V$ , $I_F = 30A$ , $di/dt = 300A/\mu s$	44		nC
t <sub>rr</sub>	Reverse Recovery Time	$V_{dd} = 13.5V$ , $I_F = 30A$ , $di/dt = 300A/\mu s$	35		ns

## THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

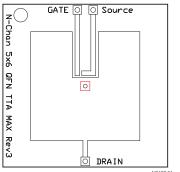
	PARAMETER				UNIT
R <sub>θJC</sub>	R <sub>θJC</sub> Thermal Resistance Junction to Case <sup>(1)</sup>				°C/W
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient <sup>(1)(2)</sup>			50	°C/W

<sup>(1)</sup> R  $_{\theta JC}$  is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 x 1.5 in 0.060 inch thick FR4 board. R  $_{\theta JC}$  is specified by design while R  $_{\theta JA}$  is determined by the user's board design.

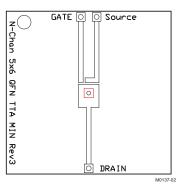
(2) Device mounted on FR4 Material with 1 inch<sup>2</sup> of 2 oz. Cu.



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Max  $R_{\theta JA} = 50^{\circ}$ C/W when mounted on 1inch<sup>2</sup> of 2 oz. Cu.



Max  $R_{\theta JA} = 122^{\circ}C/W$  when mounted on minimum pad area of 2 oz. Cu.

## TYPICAL MOSFET CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

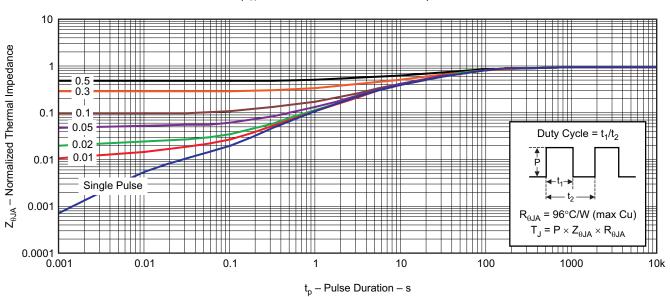


Figure 1. Transient Thermal Impedance

# TEXAS INSTRUMENTS

## **TYPICAL MOSFET CHARACTERISTICS (continued)**

(T<sub>A</sub> = 25°C unless otherwise stated)

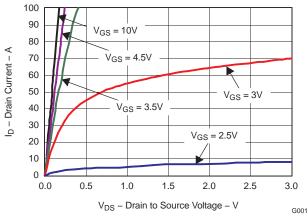


Figure 2. Saturation Characteristics

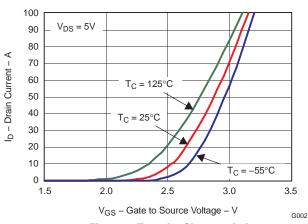


Figure 3. Transfer Characteristics

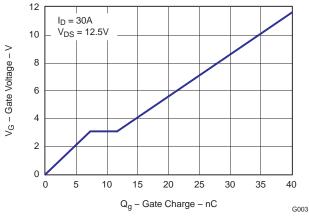


Figure 4. Gate Charge

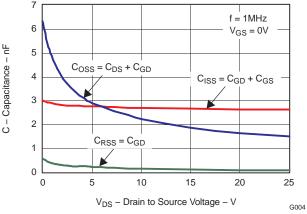


Figure 5. Capacitance

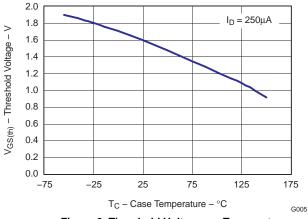


Figure 6. Threshold Voltage vs. Temperature

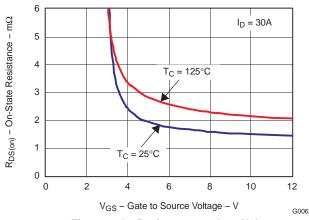


Figure 7. On Resistance vs. Gate Voltage

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## TYPICAL MOSFET CHARACTERISTICS (continued)

(T<sub>A</sub> = 25°C unless otherwise stated)

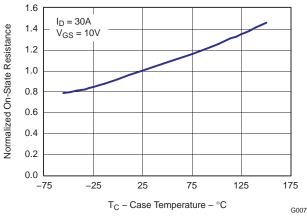


Figure 8. On Resistance vs. Temperature

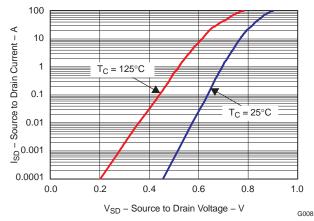


Figure 9. Typical Diode Forward Voltage

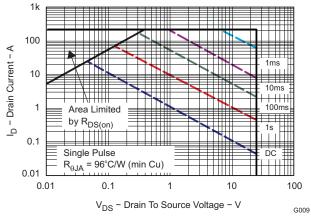


Figure 10. Maximum Safe Operating Area

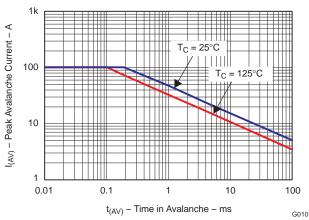


Figure 11. Single Pulse Unclamped Inductive Switching

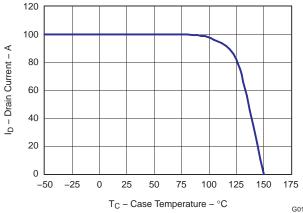
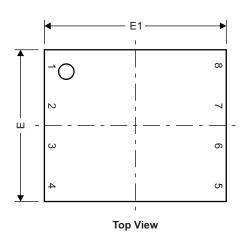


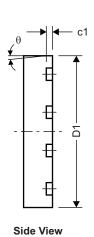
Figure 12. Maximum Drain Current vs. Temperature

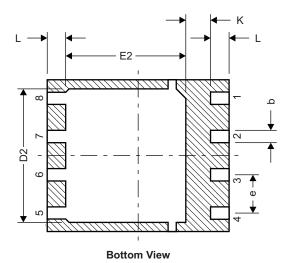


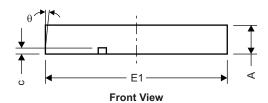
## **MECHANICAL DATA**

## **Q5 Package Dimensions**









M0140-01

DIM	MILLIM	IETERS	INC	HES
DIW	MIN	MAX	MIN	MAX
Α	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
С	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
е	1.27 TYP		0.0	50
K	0.760		0.030	
L	0.510	0.710	0.020	0.028
θ	0.00			



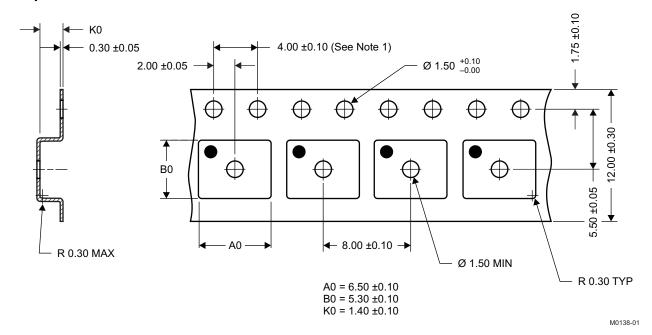
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Recommende	d PCB Pattern
F6 - F	1 F7
84 F10	M0139-01  4  7  4  7  7  7  7  7  7  7  7  7  7

MIN 6.205	MAX 6.305	MIN	MAX
	6.305		
		0.244	0.248
4.460	4.560	0.176	0.180
4.460	4.560	0.176	0.180
0.650	0.700	0.026	0.028
0.620	0.670	0.024	0.026
0.630	0.680	0.025	0.027
0.700	0.800	0.028	0.031
0.650	0.700	0.026	0.028
0.620	0.670	0.024	0.026
4.900	5.000	0.193	0.197
4.460	4.560	0.176	0.180
	4.460 0.650 0.620 0.630 0.700 0.650 0.620 4.900	4.460     4.560       0.650     0.700       0.620     0.670       0.630     0.680       0.700     0.800       0.650     0.700       0.620     0.670       4.900     5.000	4.460     4.560     0.176       0.650     0.700     0.026       0.620     0.670     0.024       0.630     0.680     0.025       0.700     0.800     0.028       0.650     0.700     0.026       0.620     0.670     0.024       4.900     5.000     0.193

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

## **Q5 Tape and Reel Information**



## Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible



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## **Package Marking Information**

#### Location

## 1st Line

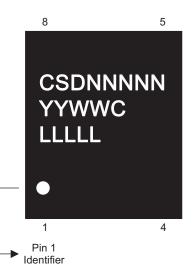
CSD = Fixed Characters
NNNNN = Product Code
2nd Line (Date Code)

YY = Last 2 digits of the Year
WW = 2-digit Work Week
C = Country of Origin
> Philippines = P

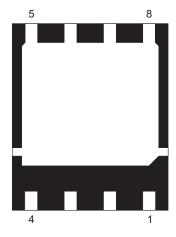
> Taiwan = T > China = C

## 3rd Line

LLLL = Last 5 digits of the Wafer Lot #



Prinduit Filder Link s): CSD164 140 5



M0141-01



#### PACKAGE OPTION ADDENDUM

2-Feb-2010 www.ti.com

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins P	ackage Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CSD16414Q5	ACTIVE	SON	DQH	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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